NSN 5961-01-229-0352

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-229-0352 **Overall Length:** 4.180 inches **Overall Diameter:** 1.031 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-8 **Mounting Method:** Threaded stud **Features Provided:** Reverse polarity Thready Qty Per Inch (tpi): 24 **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 275.00 amperes collector current, dc of standard range **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli